#5/3-1-02 Par And

Docket No.: M4065.0475

(PATENT)

## IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Inse Patent Application of:

Application No.: 09/938,672

Group Art Unit: 2814

Filed: August 27, 2001

Examiner: unknown

For: METHOD FOR DUAL CELL COMMON ELECTRODE PCRAM MEMORY DEVICE

## PRELIMINARY AMENDMENT

Box Non-Fee Amendment Commissioner for Patents Washington, DC 20231

Dear Sir:

In response to the Notice of Omitted Item mailed November 11, 2001, please amend the above-identified application as follows.

## IN THE SPECIFICATION:

Please replace paragraph [0005] with the following rewritten paragraph:

[0005] The foregoing and other features and advantages of the invention will become more apparent from the detailed description of the exemplary embodiments of the invention given below with reference to the accompanying drawings in which:

Fig. 1 shows early steps in the fabrication of a PCRAM cell of the present invention;

Fig. 2 shows the fabrication steps for a PCRAM cell of the present invention subsequent to those shown in Fig. 1;